#### SILICON (Si) POWER MOSFET A CED840A



CET MOS

# **CED840A**

## 500V 🛦 0.68Ω 🛦 7.5A 🛦 Si MOSFET

SILICON Si MOSFET ▲ THT type N-channel enhancement mode UL94V-0 rated flame retardant epoxy TO251 (E-PAK) package Super high dense cell density for extremely low R<sub>DS(ON)</sub> High power and current handling capability





FREE

RoHS

REACH

#### **MAXIMUM RATINGS**

Parameter (T <sub>c</sub> = 25°C, unless otherwise noted)		Characteristics
Drain-Source Voltage	V <sub>DS</sub>	500V
Gate-Source Voltage	V <sub>GS</sub>	±30V
Continuous Drain Current at T <sub>c</sub> = 25°C	Ι <sub>D</sub>	7.5A
Continuous Drain Current at T <sub>c</sub> = 100°C	Ι <sub>D</sub>	4.7A
Pulsed Drain Current Note 1	I <sub>DM</sub>	30A
Maximum Power Dissipation at T <sub>c</sub> = 25°C	PD	107W
Power Dissipation Derating above 25°C	ΔP <sub>D</sub>	0.85W/°C
Single Pulsed Avalanche Energy Note 5	E <sub>AS</sub>	196mJ
Single Pulsed Avalanche Current Note 5	I <sub>AS</sub>	7.5A
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55°C to +175°C

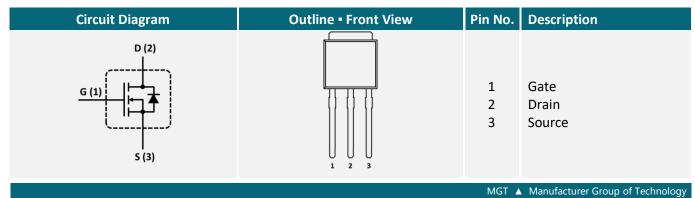
#### THERMAL CHARACTERISTICS

Parameter	Symbol	Limit
Thermal Resistance, Junction-to-Case	R <sub>TH_JC</sub>	1.4°C/W
Thermal Resistance, Junction-to-Ambient	R <sub>th_ja</sub>	50°C/W

#### **APPLICATIONS**

General Lighting	Industrial	Motors	Power	UPS
LED & CCFL	Inverters	& Drives	Supplies	
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#### **PIN DESCRIPTION**



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#### **ELECTRICAL CHARACTERISTICS** A T<sub>c</sub> = 25°C, unless otherwise noted

ltem	Condition	Symbol	Min.	Тур.	Max.	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV <sub>DSS</sub>	500			V
Zero Gate Voltage Drain Current	$V_{DS}$ = 500V, $V_{GS}$ = 0V	I <sub>DSS</sub>			1	μΑ
Gate Body Leakage Current, Forward	$V_{GS} = 30V, V_{DS} = 0V$	I <sub>GSSF</sub>			100	nA
Gate Body Leakage Current, Reverse	$V_{GS} = -30V, V_{DS} = 0V$	I <sub>GSSR</sub>			-100	nA
On Characteristics Note 2						
Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250 \mu A$	V <sub>GS(th)</sub>	2		4	V
Static Drain-Source On-Resistance	$V_{GS}$ = 10V, $I_{D}$ = 4.3A	R <sub>DS(ON)</sub>		0.68	0.85	Ω
Dynamic Characteristics Note 3						
Input Capacitance	$V_{DS}$ = 25V, $V_{GS}$ = 0V, f = 1MHz	CISS		1580		рF
Output Capacitance	$V_{DS}$ = 25V, $V_{GS}$ = 0V, f = 1MHz	Coss		125		рF
Reverse Transfer Capacitance	$V_{DS}$ = 25V, $V_{GS}$ = 0V, f = 1MHz	C <sub>RSS</sub>		15		pF
Switching Characteristics Note 3						
Turn-On Delay Time	$V_{\text{DD}}$ = 250V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 7A, $R_{\text{G}(\text{ext})}$ = 9.1 $\Omega$	t <sub>D(ON)</sub>		20		ns
Turn-On Rise Time	$V_{\text{DD}}$ = 250V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 7A, $R_{\text{G}(\text{ext})}$ = 9.1 $\Omega$	t <sub>R</sub>		5		ns
Turn-Off Delay Time	$V_{\text{DD}}$ = 250V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 7A, $R_{\text{G}(\text{ext})}$ = 9.1 $\Omega$	$t_{D(OFF)}$		38		ns
Turn-Off Fall Time	$V_{\text{DD}}$ = 250V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 7A, $R_{\text{G}(\text{ext})}$ = 9.1 $\Omega$	t <sub>F</sub>		4		ns
Total Gate Charge	$V_{\text{DD}}$ = 400V, $V_{\text{GS}}$ = 10V, $I_{\text{D}}$ = 7A	Q <sub>G</sub>		25		nC
Gate Source Charge	$V_{DD}$ = 400V, $V_{GS}$ = 10V, $I_D$ = 7A	Q <sub>GS</sub>		5		nC
Gate Drain Charge	$V_{DD}$ = 400V, $V_{GS}$ = 10V, $I_D$ = 7A	$\mathbf{Q}_{GD}$		6		nC
Drain-Source Diode Characteristics a	nd Maximum Ratings					
Drain-Source Diode Forward Current		ls			7	А
Drain-Source Diode Forward Voltage Note 2	V <sub>GS</sub> = 0V, I <sub>S</sub> = 7A	$V_{\text{SD}}$			1.5	V

#### Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2: Surface Mounted on FR4 Board, t < 10 sec.
- 3: Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4: Guaranteed by design, not subject to production testing.
- 5: L = 7mH,  $I_{AS} = 7.5A$ ,  $V_{DD} = 50V$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^{\circ}C$

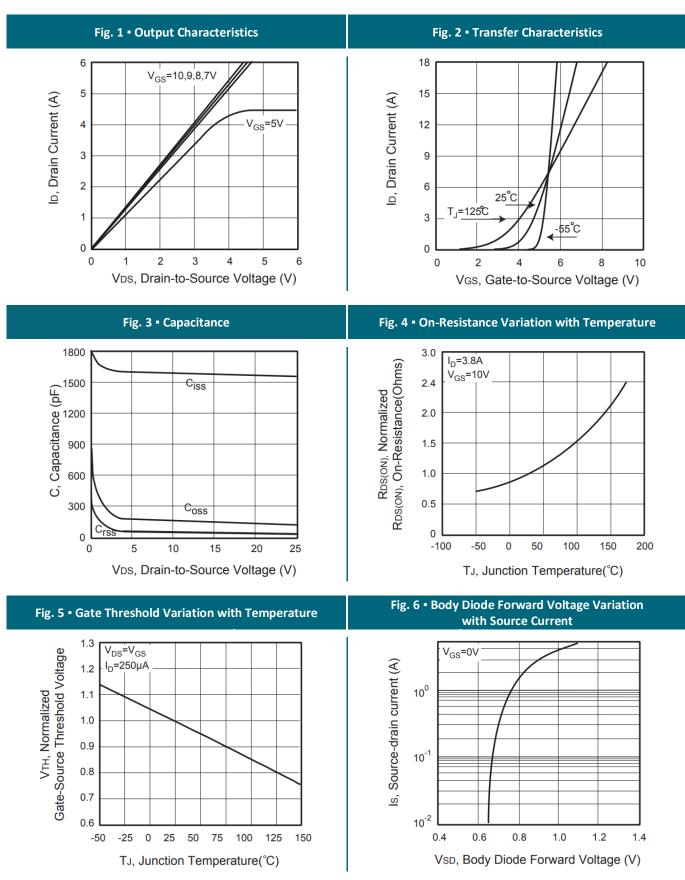


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#### **REFERENCE DATA ▲ TYPICAL DEVICE PERFORMANCE**

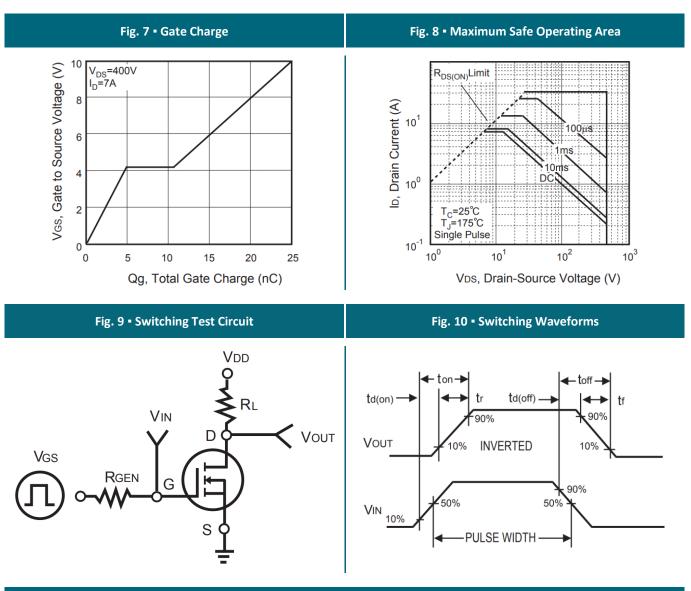


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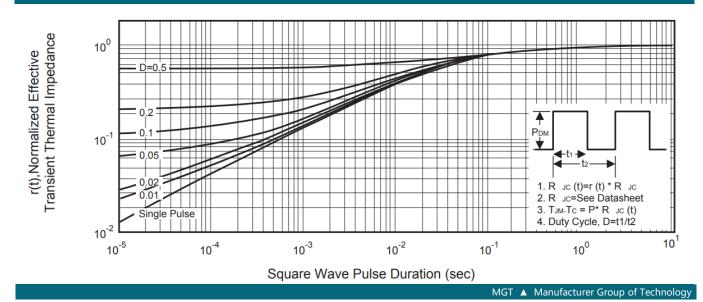


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#### **REFERENCE DATA A TYPICAL DEVICE PERFORMANCE**



#### Fig. 11 - Normalized Thermal Transient Impedance Curve

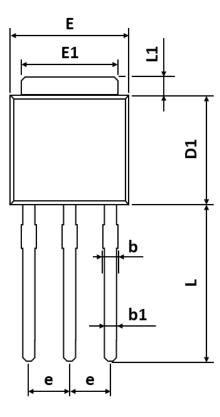


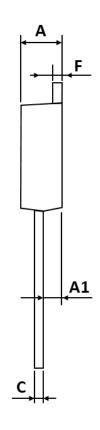
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#### **PACKAGE OUTLINE**





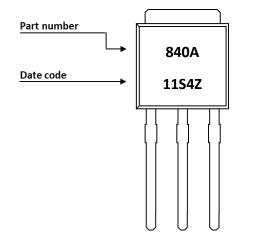
Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
А	2.180	-	2.400
A1	0.860	-	1.500
b	0.700	-	0.960
b1	0.700	-	0.860
С	0.400	-	0.610
D1	5.400	-	6.630
E	6.050	-	7.010
E1	4.950	-	5.460
е	1.980	-	2.590
F	0.400	-	0.890
L	8.500	-	9.650
L1	0.500	-	1.800

#### **ORDERING INFORMATION**

Part Number	Package	Packing	Tube Qty.	Inner Box Qty.	Outer Box Qty.
CED840A	TO251 (E-PAK)	Tube	80pcs	4,000pcs	16,000pcs

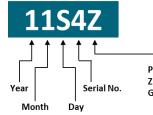
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## **PART MARKING**



## DATE CODE

Example: 11S4Z



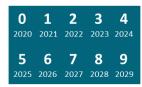
| Product Type Z: Pb-free G: Green Product

	Coding list for "Day"								
<b>1</b>	<b>2</b>	<b>3</b>	<b>4</b>	<b>5</b>	<b>6</b>	<b>7</b>	<b>8</b>	<b>9</b>	<b>A</b>
01	02	03	04	05	06	07	08	09	10
<b>B</b>	<b>C</b>	<b>D</b>	<b>E</b>	<b>F</b>	<b>G</b>	<b>H</b>	┃	<b>J</b>	<b>K</b>
11	12	13	14	15	16	17	18	19	20
<b>L</b>	<b>M</b>	<b>N</b>	<b>O</b>	<b>P</b>	<b>Q</b>	<b>R</b>	<b>S</b>	<b>T</b>	<b>U</b>
21	22	23	24	25	26	27	28	29	30
<b>V</b> 31									

Coding list for "Month"

<b>1</b> Jan	<b>2</b> Feb	<b>4</b> Apr	<b>5</b> May	
<b>7</b>	<b>8</b>	<b>A</b>	<b>B</b>	<b>C</b>
Jul	Aug	Oct	Nov	Dec

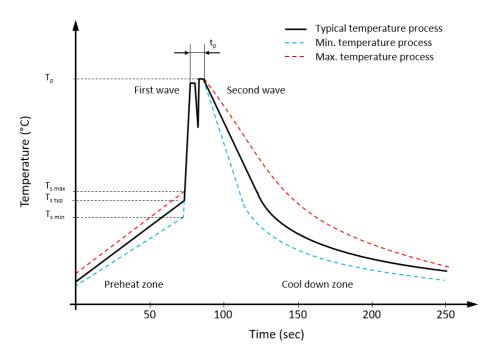
Coding list for "Year"







### **RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE**



#### Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

Profile Features		Value 🛦 Sn-Pb Assembly	Value 🔺 Pb-free Assembly
Preheat temperature min.	$T_{s min}$	100 °C	100 °C
Preheat temperature typical	T <sub>s typ</sub>	120 °C	120 °C
Preheat temperature max.	$T_{s max}$	130 °C	130 °C
Preheat time $t_s$ from $T_{s min}$ to $T_{s max}$	ts	70 seconds	70 seconds
Peak temperature	Tp	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	t <sub>p</sub>	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second
Time 25°C to 25°C		4 minutes	4 minutes



#### **REVISION TABLE**

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

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